

TENTATIVE

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74VCX04FT**

## **LOW-VOLTAGE HEX INVERTER WITH 3.6 V TOLERANT INPUTS AND OUTPUTS**

The TC74VCX04FT is a high performance CMOS INVERTER.

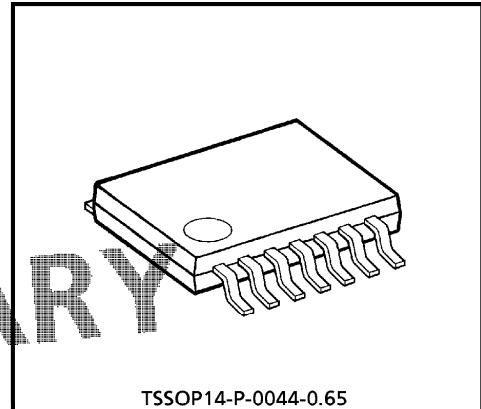
Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

All inputs are equipped with protection circuits against static discharge.

### **FEATURES**

- Low Voltage Operation :  $V_{CC} = 1.8\sim 3.6$  V
- High Speed Operation :  $t_{pd} = 2.8$  ns (max) at  $V_{CC} = 3.0\sim 3.6$  V  
 $t_{pd} = 3.7$  ns (max) at  $V_{CC} = 2.3\sim 2.7$  V  
 $t_{pd} = 7.4$  ns (max) at  $V_{CC} = 1.8$  V
- Output Current :  $I_{OH}/I_{OL} = \pm 24$  mA (min) at  $V_{CC} = 3.0$  V  
 $I_{OH}/I_{OL} = \pm 18$  mA (min) at  $V_{CC} = 2.3$  V  
 $I_{OH}/I_{OL} = \pm 6$  mA (min) at  $V_{CC} = 1.8$  V
- Latch-up Performance :  $\pm 300$  mA
- ESD Performance : Human Body Model  $> \pm 2000$  V  
: Machine Model  $> \pm 200$  V
- Package : TSSOP  
(Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.



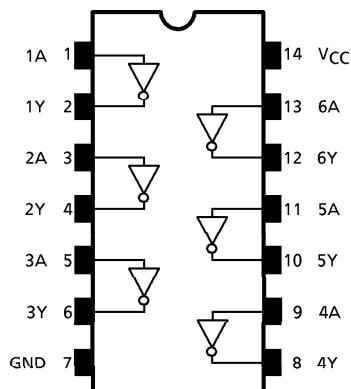
TSSOP14-P-0044-0.65

Weight : 0.06 g (Typ.)

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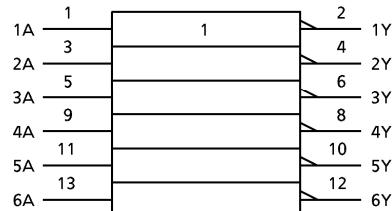
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## PIN ASSIGNMENT



(TOP VIEW)

## IEC LOGIC SYMBOL



## TRUTH TABLE

INPUTS	OUTPUTS
A	Y
L	H
H	L

PRELIMINARY

## MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	V <sub>CC</sub>	-0.5~4.6	V
DC Input Voltage	V <sub>IN</sub>	-0.5~4.6	V
DC Output Voltage	V <sub>OUT</sub>	-0.5~4.6 (Note 1)	V
		-0.5~V <sub>CC</sub> + 0.5 (Note 2)	
Input Diode Current	I <sub>IK</sub>	-50	mA
Output Diode Current	I <sub>OK</sub>	±50 (Note 3)	mA
DC Output Current	I <sub>OUT</sub>	±50	mA
Power Dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> / Ground Current	I <sub>CC</sub> / I <sub>GND</sub>	±100	mA
Storage Temperature	T <sub>stg</sub>	-65~150	°C

(Note 1): V<sub>CC</sub> = 0 V(Note 2): High or Low State. I<sub>OUT</sub> absolute maximum rating must be observed.(Note 3): V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

## RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	$V_{IN}$	-0.3~3.6	V
Output Voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH}/I_{OL}$	$\pm 24$ (Note 7)	mA
		$\pm 18$ (Note 8)	
		$\pm 6$ (Note 9)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise And Fall Time	$dt/dv$	0~10 (Note 10)	ns/V

(Note 4): Data Retention Only

(Note 5):  $V_{CC} = 0$  V

(Note 6): High or Low State

(Note 7):  $V_{CC} = 3.0$ ~3.6 V(Note 8):  $V_{CC} = 2.3$ ~2.7 V(Note 9):  $V_{CC} = 1.8$  V(Note 10):  $V_{IN} = 0.8$ ~2.0 V,  $V_{CC} = 3.0$  V

## ELECTRICAL CHARACTERISTICS

DC characteristics ( $T_a = -40$ ~85°C,  $2.7$  V <  $V_{CC} \leq 3.6$  V)

PARAMETER	SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT	
Input Voltage	"H" Level	$V_{IH}$		2.7~3.6	2.0	—	V	
	"L" Level	$V_{IL}$		2.7~3.6	—	0.8		
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IL}$	$I_{OH} = -100 \mu A$	2.7~3.6	$V_{CC} - 0.2$	V	
				$I_{OH} = -12$ mA	2.7	2.2		
				$I_{OH} = -18$ mA	3.0	2.4		
				$I_{OH} = -24$ mA	3.0	2.2		
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$	$I_{OL} = 100 \mu A$	2.7~3.6	—	V	
				$I_{OL} = 12$ mA	2.7	—		
				$I_{OL} = 18$ mA	3.0	—		
				$I_{OL} = 24$ mA	3.0	—		
Input Leakage Current	$I_{IN}$	$V_{IN} = 0$ ~3.6 V		2.7~3.6	—	$\pm 5.0$	$\mu A$	
Power Off Leakage Current	$I_{OFF}$	$V_{IN}, V_{OUT} = 0$ ~3.6 V		0	—	10.0	$\mu A$	
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND		2.7~3.6	—	20.0	$\mu A$	
		$V_{CC} \leq V_{IN} \leq 3.6$ V		2.7~3.6	—	$\pm 20.0$		
Increase In $I_{CC}$ Per Input	$\Delta I_{CC}$	$V_{IH} = V_{CC} - 0.6$ V		2.7~3.6	—	750	$\mu A$	

**ELECTRICAL CHARACTERISTICS**DC characteristics ( $T_a = -40\sim85^\circ C$ ,  $2.3 V \leq V_{CC} \leq 2.7 V$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT	
Input Voltage	"H" Level	$V_{IH}$				2.3~2.7	1.6	—	
	"L" Level	$V_{IL}$				2.3~2.7	—	0.7	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IL}$	$I_{OH} = -100 \mu A$	2.3~2.7	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -6 mA$	2.3	2.0	—		
				$I_{OH} = -12 mA$	2.3	1.8	—	V	
				$I_{OH} = -18 mA$	2.3	1.7	—		
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$	$I_{OL} = 100 \mu A$	2.3~2.7	—	0.2	$\mu A$	
				$I_{OL} = 12 mA$	2.3	—	0.4		
				$I_{OL} = 18 mA$	2.3	—	0.6	$\mu A$	
Input Leakage Current	$I_{IN}$	$V_{IN} = 0\sim3.6 V$		2.3~2.7		—	$\pm 5.0$		
Power Off Leakage Current	$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim3.6 V$		0		—	10.0	$\mu A$	
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND		2.3~2.7		—	20.0	$\mu A$	
		$V_{CC} < V_{IN} \leq 3.6 V$		2.3~2.7		—	$\pm 20.0$		

PRELIMINARY

**ELECTRICAL CHARACTERISTICS**DC characteristics ( $T_a = -40\text{~}85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT
Input Voltage	"H" Level	$V_{IH}$			1.8~2.3	$0.7 \times V_{CC}$	—	V
	"L" Level	$V_{IL}$			1.8~2.3	—	$0.2 \times V_{CC}$	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IL}$	$I_{OH} = -100\text{ }\mu\text{A}$	1.8	$V_{CC} - 0.2$	—	V
				$I_{OH} = -6\text{ mA}$	1.8	1.4	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$	$I_{OL} = 100\text{ }\mu\text{A}$	1.8	—	0.2	
				$I_{OL} = 6\text{ mA}$	1.8	—	0.3	
Input Leakage Current	$I_{IN}$		$V_{IN} = 0\text{~}3.6\text{ V}$		1.8	—	$\pm 5.0$	$\mu\text{A}$
Power Off Leakage Current	$I_{OFF}$		$V_{IN}, V_{OUT} = 0\text{~}3.6\text{ V}$		0	—	10.0	$\mu\text{A}$
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND			1.8	—	20.0	$\mu\text{A}$
		$V_{CC} \leq V_{IN} \leq 3.6\text{ V}$			1.8	—	$\pm 20.0$	

**PRELIMINARY**AC characteristics ( $T_a = -40\text{~}85^\circ\text{C}$ , Input  $t_r = t_f = 2.0\text{ ns}$ ,  $C_L = 30\text{ pF}$ ,  $R_L = 500\text{ }\Omega$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	MIN	MAX	UNIT
Propagation Delay Time	$t_{pLH}$ $t_{pHL}$	(Fig.1, 2)			1.8	1.0	7.4	ns
					$2.5 \pm 0.2$	0.8	3.7	
					$3.3 \pm 0.3$	0.6	2.8	
Output To Output Skew	$t_{osLH}$ $t_{osHL}$	(Note 11)			1.8	—	0.5	ns
					$2.5 \pm 0.2$	—	0.5	
					$3.3 \pm 0.3$	—	0.5	

For  $C_L = 50\text{ pF}$ , add approximately 300 ps to the AC maximum specification.

(Note 11): Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLM} - t_{pHLn}|)$$

Dynamic switching characteristics ( $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 2.0 \text{ ns}$ ,  $C_L = 30 \text{ pF}$ )

PARAMETER	SYMBOL	TEST CONDITION		TYP.	UNIT
		$V_{CC} (\text{V})$			
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$V_{IH} = 1.8 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	1.8	0.25	V
		$V_{IH} = 2.5 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	2.5	0.6	
		$V_{IH} = 3.3 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	3.3	0.8	
Quiet Output Minimum Dynamic $V_{OL}$	$V_{OLV}$	$V_{IH} = 1.8 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	1.8	-0.25	V
		$V_{IH} = 2.5 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	2.5	-0.6	
		$V_{IH} = 3.3 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	3.3	-0.8	
Quiet Output Minimum Dynamic $V_{OH}$	$V_{OHV}$	$V_{IH} = 1.8 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	1.8	1.5	V
		$V_{IH} = 2.5 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	2.5	1.9	
		$V_{IH} = 3.3 \text{ V}$ , $V_{IL} = 0 \text{ V}$ (Note 12)	3.3	2.2	

(Note 12): Parameter guaranteed by design.

# PRELIMINARY

Capacitive characteristics ( $T_a = 25^\circ\text{C}$ )

PARAMETER	SYMBOL	TEST CONDITION		TYP.	UNIT
		$V_{CC} (\text{V})$			
Input Capacitance	$C_{IN}$	—	1.8, 2.5, 3.3	6	pF
Power Dissipation Capacitance	$C_{PD}$	$f_{IN} = 10 \text{ MHz}$ (Note 13)	1.8, 2.5, 3.3	20	pF

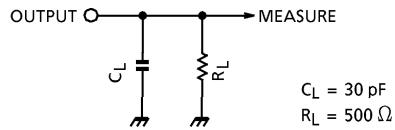
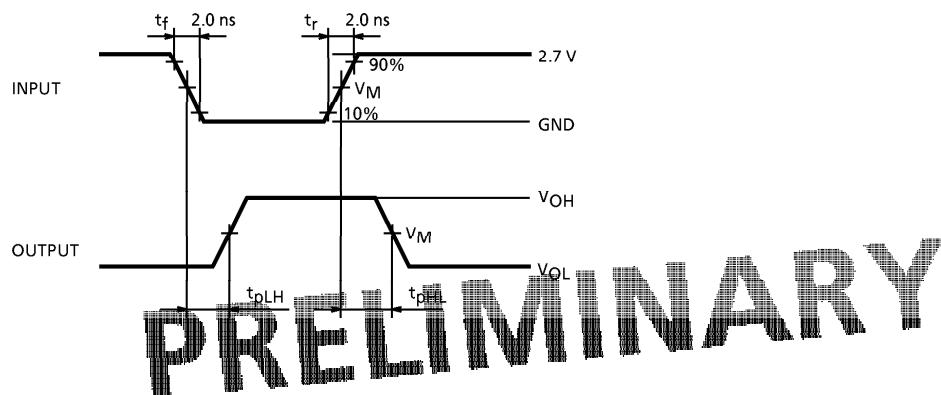
(Note 13):  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

**TEST CIRCUIT**

Fig.1

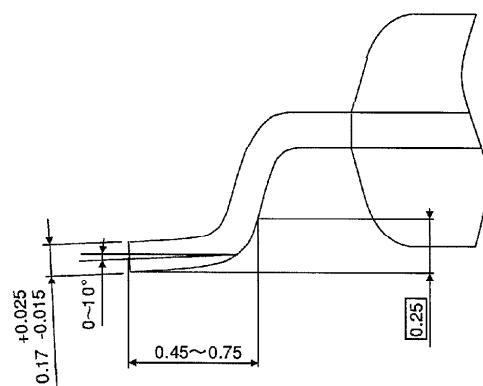
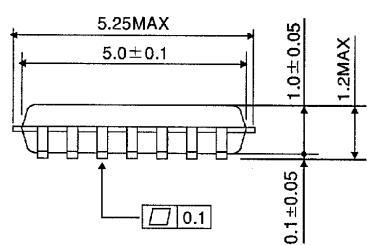
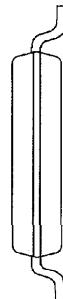
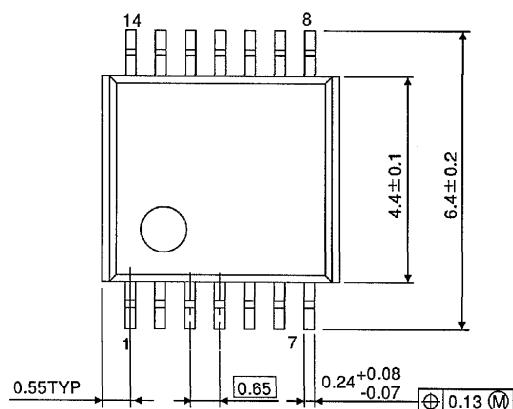
**AC WAVEFORM**Fig.2 t<sub>pLH</sub>, t<sub>pHL</sub>

SYMBOL	V <sub>CC</sub>		
	3.3 ± 0.3 V	2.5 ± 0.2 V	1.8 V
V <sub>IH</sub>	2.7V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>M</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2

## OUTLINE DRAWING

TSSOP14-P-0044-0.65

Unit : mm



Weight : 0.06 g (Typ.)